

IN THE CLAIMS

Please amend claims 1-3, 5-9, and 14-17 as follows. All claims have been provided as a courtesy to the Examiner.

1. (Amended) A memory module, comprising:
a plurality of memory devices; and
a memory module controller configured to receive a first memory transaction
in a first format from a first memory bus, and [to control] to convert the first memory
transaction into a second memory transaction in a second format [access to] for
the plurality of memory devices, the second format of the second memory
transaction being different from the first format of the first memory transaction.

2. (Amended) The memory module of claim 1, wherein the memory module
controller is also configured to reformat [receives] the first memory transaction in
[a] the first format [, and reformats the first memory transaction] into [a] the second
memory transaction in the second format, and [the memory module controller
providing] to provide the [reformatted] second memory transaction to at least one
of the plurality of memory devices.

a 1 3. (Amended) The memory module of claim 1, further comprising:
2 a second memory bus coupled between the memory module controller and
3 the plurality of memory devices.

1 4. (Unchanged) The memory module of claim 3, wherein the second memory
2 bus comprises separate address, data, and control signal lines.

a 1 5. (Amended) The memory module of claim [1] 3, wherein the second
2 memory bus comprises a signal line for a clock signal.

Sub B3 1 6. (Amended) The memory module of claim [1] 3, wherein the first memory
2 bus operates at a first data rate and the second memory bus operates at a second
3 data rate, and wherein the first data rate is different than the second data rate.

1 7. (Amended) The memory module of claim 1, wherein the first memory bus
2 includes [has] a first number of [signals] signal lines and the second memory bus
3 includes [has] a second number of signal lines, and wherein the first number [of
4 signal lines] is different than the second number [of signal lines].

Sub B3 1 8. (Amended) The memory module of claim 1, wherein the memory module
2 controller comprises:
3 request handling circuitry [structured] configured to receive the first memory
4 transaction from the first memory bus; and

5 control logic coupled to the request handling circuitry and configured to
6 [reformatting] reformat the first memory transaction[, the memory module controller
7 providing] and to provide the reformatted first memory transaction to at least one of
8 the plurality of memory devices.

1 9. (Amended) The memory module of claim 1, wherein the first memory bus
2 [carries] is configured to carry time-multiplexed data and address information, and
3 the second memory bus includes separate address and data lines.

1 10. (Unchanged) The memory module of claim 1, wherein the memory module
2 is a dual in-line first memory module (DIMM).

1 11. (Unchanged) The memory module of claim 1, wherein the memory module
2 is a single in-line first memory module (SIMM).

1 12. (Unchanged) The memory module of claim 1, wherein the plurality of
2 memory devices comprise volatile memory devices.

1 13. (Unchanged) The memory module of claim 1, wherein the plurality of
2 memory devices comprise nonvolatile memory devices.

1 14. (Amended) The memory module of claim 1, wherein the memory module
2 controller is configured to generate [generates] a handshake signal that indicates

3 when the memory module controller is communicating data to the system memory
4 controller.

1 15. (Amended) The memory module of claim 1, wherein the first memory
2 transaction is a write transaction.

1 16. (Amended) The memory module of claim 1, wherein the first memory
2 transaction is a read transaction.

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1 17. (Amended) A memory module, comprising:
2 a plurality of memory devices; and
3 a memory module controller coupled to [a] the plurality of memory devices,
4 [wherein] the memory module controller being configured to receive [receives] a
5 first memory transaction in a first format from [the] a memory bus [in a first format],
6 and to convert the first memory transaction into a second memory transaction in a
7 second format, and to provide [provides a] the second memory transaction in [a]
8 the second format to at least one of the [second] plurality of memory devices.
